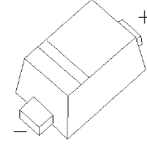


BAT54X Schottky Barrier Diode

FEATURES

- Extremely Fast Switching Speed
- Low Forward Voltage

MARKING: JV



SOD-523

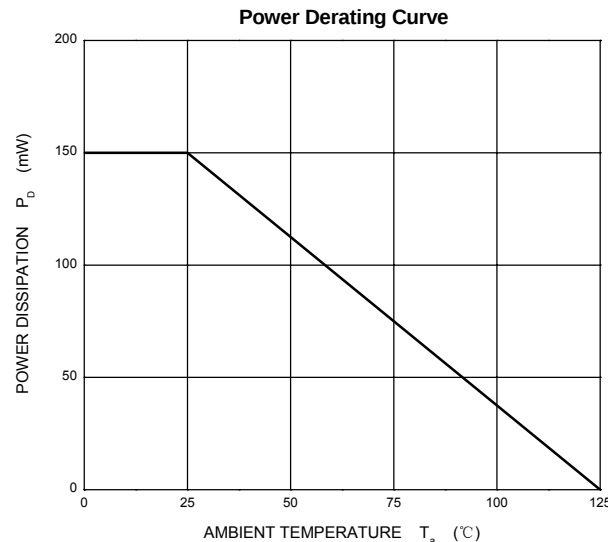
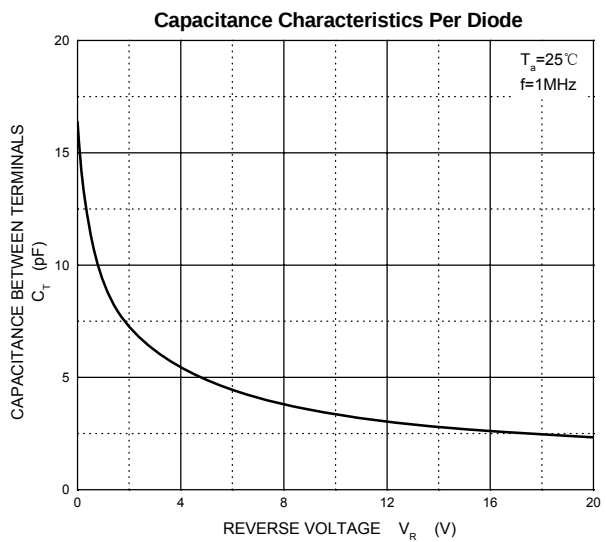
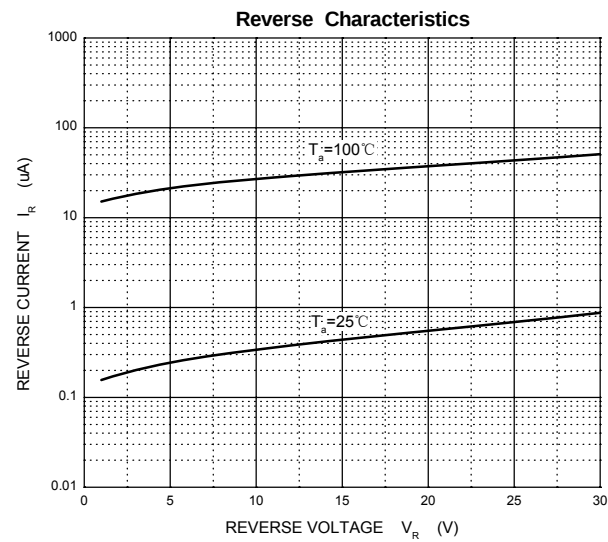
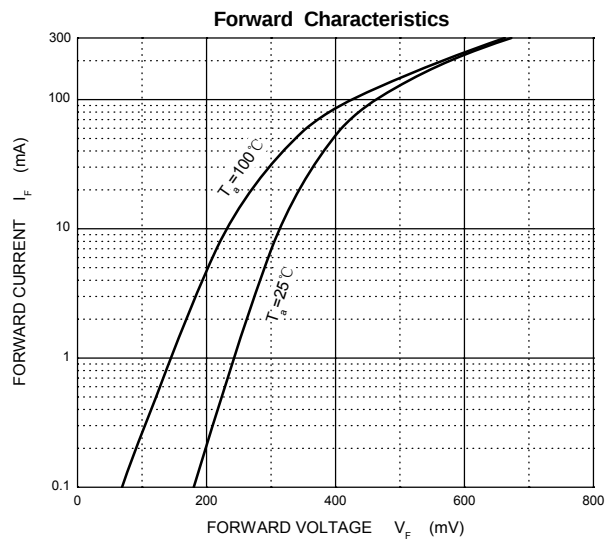
Maximum Ratings @Ta=25°C

Parameter	Symbol	Limit	Unit
Non-repetitive peak reverse voltage	V_{RM}	30	V
DC blocking voltage	V_R	21	V
Average rectified output current	I_O	100	mA
Forward continuous current	I_F	200	mA
Repetitive peak forward current	I_{FRM}	300	mA
Non-repetitive Peak Forward surge current @t=8.3ms	I_{FSM}	600	mA
Power dissipation	P_d	150	mW
Thermal resistance junction to ambient	$R_{\theta JA}$	667	°C/W
Junction temperature	T_J	125	°C
Storage temperature range	T_{STG}	-55~+150	°C

Electrical Characteristics @Ta=25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse breakdown voltage	$V_{(BR)}$	$I_R=100\mu A$	30			V
Forward voltage	V_{F1}	$I_F=0.1mA$			240	mV
	V_{F2}	$I_F=1.0mA$			320	mV
	V_{F3}	$I_F=10mA$			400	mV
	V_{F4}	$I_F=30mA$			500	mV
	V_{F5}	$I_F=100mA$			1000	mV
Reverse current	I_R	$V_R=25V$			2.0	μA
Reverse recovery time	t_{rr}	$I_F=10mA, I_R=10mA \text{ to } 1mA, R_L=100\Omega$			5.0	ns
Capacitance between terminals	C_T	$V_R=1V, f=1MHz$			10	pF

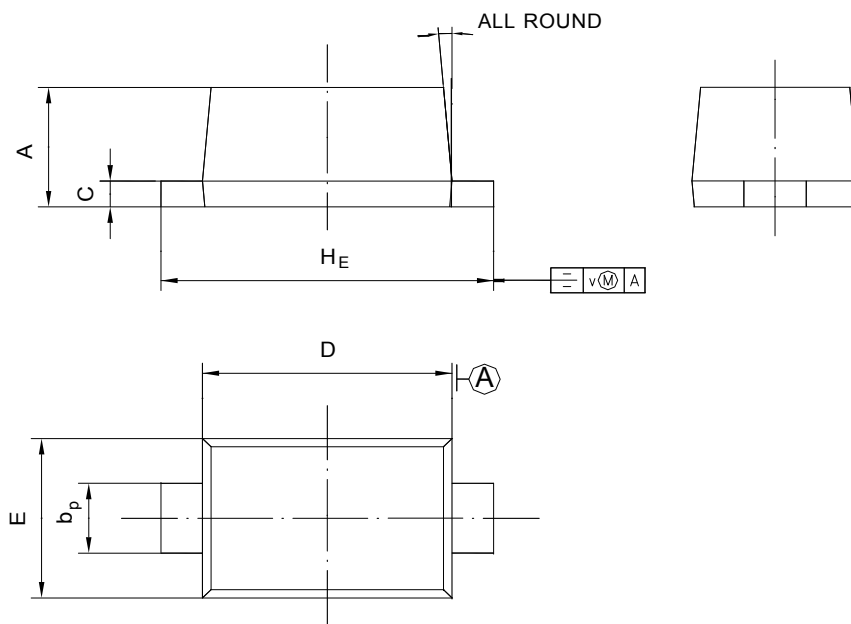
Typical Characteristics



PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-523



UNIT	A	b _p	C	D	E	H _E	V	∠
mm	0.68 0.58	0.4 0.3	0.135 0.100	1.25 1.15	0.85 0.75	1.7 1.5	0.1	5°